## MMDL101T1G

# **Schottky Barrier Diode**

Schottky barrier diodes are designed primarily for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications.

#### **Features**

- Very Low Capacitance Less than 1.0 pF @ 0 V
- Low Noise Figure 6.0 dB Typ @ 1.0 GHz
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Reverse Voltage	$V_{R}$	7.0	Vdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) @T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 1.57	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	635	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 Minimum Pad

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μA)	V <sub>(BR)R</sub>	7.0	10	-	V
Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHZ), (Note 2)*	C <sub>T</sub>	-	0.88	1.0	pF
Reverse Leakage (V <sub>R</sub> = 3.0 V)	I <sub>R</sub>	-	20	250	nAdc
Noise Figure (f = 1.0 GHz), (Note 3)*	NF	-	6.0	-	dB
Forward Voltage (I <sub>F</sub> = 10 mA)	V <sub>F</sub>	ı	0.5	0.6	Vdc

<sup>\*</sup>Notes on Next Page



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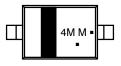
# 1.0 pF SCHOTTKY BARRIER DIODE





PLASTIC SOD-323 CASE 477 STYLE 1

#### **MARKING DIAGRAM**



4M = Device Code M = Date Code\* ■ = Pb-Free Package

(Note: Microdot may be in either location)
\*Date Code orientation may vary depending upon manufacturing location.

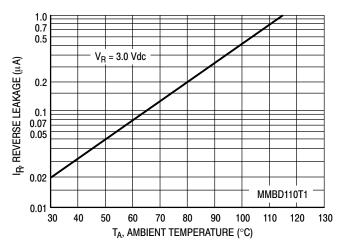
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMDL101T1G	SOD-323 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### MMDL101T1G

#### TYPICAL CHARACTERISTICS



1.0 T<sub>A</sub> = 85°C

T<sub>A</sub> = -40°C

MMBD110T1

0.1

0.3

0.4

0.5

0.6

0.7

0.8

V<sub>F</sub>, FORWARD VOLTAGE (VOLTS)

Figure 1. Reverse Leakage

Figure 2. Forward Voltage

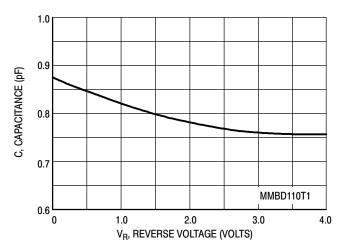


Figure 3. Capacitance

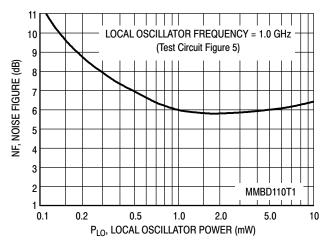


Figure 4. Noise Figure

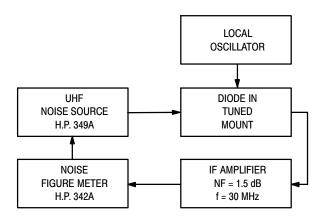
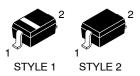


Figure 5. Noise Figure Test Circuit

### NOTES ON TESTING AND SPECIFICATIONS

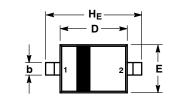
- 2.  $C_C$  and  $C_T$  are measured using a capacitance bridge (Boonton Electronics Model 75A or equivalent).
- Noise figure measured with diode under test in tuned diode mount using UHF noise source and local oscillator (LO) frequency of 1.0 GHz. The LO power is adjusted for 1.0 mW. IF amplifier NF = 1.5 dB, f = 30 MHz, see Figure 5.

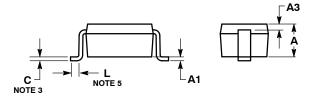


SOD-323 CASE 477-02 **ISSUE H** 

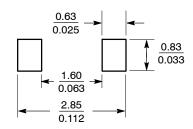
**DATE 13 MAR 2007** 

#### SCALE 4:1





#### **SOLDERING FOOTPRINT\***

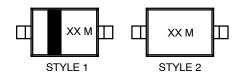


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD
- FLASH, PROTRUSIONS OR GATE BURRS.
  5. DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS				INCHES	3
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.031	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.15 REF			0.006 REF		
b	0.25	0.32	0.4	0.010	0.012	0.016
С	0.089	0.12	0.177	0.003	0.005	0.007
D	1.60	1.70	1.80	0.062	0.066	0.070
Е	1.15	1.25	1.35	0.045	0.049	0.053
L	0.08			0.003		
HE	2.30	2.50	2.70	0.090	0.098	0.105

#### **GENERIC** MARKING DIAGRAM\*



XX = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

NO POLARITY

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